

# PN4248, PN4249, PN4250

PNP SILICON AF LOW NOISE SMALL SIGNAL TRANSISTORS

PN42248, PN4249, PN4250 are PNP silicon planar transistors for AF low noise preamplifier applications.

CASE TO-92A



## ABSOLUTE MAXIMUM RATINGS

		PN4248	PN4250	PN4249
Collector-Base Voltage	-V <sub>CB0</sub>	40V	40V	60V
Collector-Emitter Voltage	-V <sub>CEO</sub>	40V	40V	60V
Emitter-Base Voltage	-V <sub>EBO</sub>	5V	5V	5V
Collector Current	-I <sub>C</sub>		50mA	
Total Power Dissipation (T <sub>C</sub> ≤ 65°C)	P <sub>tot</sub>		300mW	
(T <sub>A</sub> ≤ 25°C)			200mW	
Operating Junction & Storage Temperature	T <sub>j</sub> , T <sub>stg</sub>		-55 to 125°C	

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	PN4248		PN4249		PN4250		UNIT	TEST CONDITIONS
		MIN	MAX	MIN	MAX	MIN	MAX		
Collector-Base Breakdown Voltage	-V <sub>CB0</sub>	40		60		40		V	-I <sub>C</sub> =0.01mA I <sub>E</sub> =0
Collector-Emitter Breakdown Voltage	-V <sub>CES</sub>	40		60		40		V	-I <sub>C</sub> =0.01mA V <sub>BE</sub> =0
Collector-Emitter Breakdown Voltage	-LV <sub>CEO</sub>	40		60		40		V	-I <sub>C</sub> =5mA (Pulsed) I <sub>B</sub> =0
Emitter-Base Breakdown Voltage	-V <sub>EBO</sub>	5		5		5		V	-I <sub>E</sub> =0.01mA I <sub>C</sub> =0
Collector Cutoff Current	-I <sub>CBO</sub>		10		10		10	nA	-V <sub>CB</sub> =40V I <sub>E</sub> =0
			3		3		3	μA	-V <sub>CB</sub> =40V I <sub>E</sub> =0 T <sub>A</sub> =65°C
Emitter Cutoff Current	-I <sub>EBO</sub>		20		20		20	nA	-V <sub>EB</sub> =3V I <sub>C</sub> =0
Collector-Emitter Saturation Voltage	-V <sub>CE(sat)</sub>		0.25		0.25		0.25	V	-I <sub>C</sub> =10mA -I <sub>B</sub> =0.5mA
Base-Emitter Saturation Voltage	-V <sub>BE(sat)</sub>		0.9		0.9		0.9	V	-I <sub>C</sub> =10mA -I <sub>B</sub> =0.5mA
D.C. Current Gain	H <sub>FE</sub>		50		100 300		250 700		-I <sub>C</sub> =100μA -V <sub>CE</sub> =5V
			50		100		250		-I <sub>C</sub> =1mA -V <sub>CE</sub> =5V
			50		100		250		-I <sub>C</sub> =10mA -V <sub>CE</sub> =5V



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PARAMETER	SYMBOL	PN4248		PN4249		PN4250		UNIT	TEST CONDITIONS
		MIN	MAX	MIN	MAX	MIN	MAX		
Small Signal Current Gain	$h_{fe}$	50	1000	100	550	250	800		$-I_C=1mA$ $-V_{CE}=5V$ $f=1kHz$
Input Impedance	$h_{ie}$			2.5	17	6	20	$K\Omega$	$-I_C=1mA$ $-V_{CE}=5V$ $f=1kHz$
Output Admittance	$h_{oe}$			5	40	5	50	$\mu S$	$-I_C=1mA$ $-V_{CE}=5V$ $f=1kHz$
Voltage Feedback Ratio	$h_{re}$				10		10	$\times 10^{-4}$	$-I_C=1mA$ $-V_{CE}=5V$ $f=1kHz$
Current Gain-Bandwidth Product	$f_T$	40		40		50		MHz	$-I_C=0.5mA$ $-V_{CE}=5V$
Collector-Base Capacitance	$C_{ob}$		6		6		6	pF	$-V_{CB}=5V$ $I_E=0$ $f=1MHz$
Emitter-Base Capacitance	$C_{ib}$		16		16		16	pF	$-V_{EB}=0.5V$ $I_C=0$ $f=1MHz$
Noise Figure	NF				3		2	dB	$-I_C=20\mu A$ $-V_{CE}=5V$ $R_G=10K\Omega$ $f=1kHz$
					3		2	dB	$-I_C=20\mu A$ $-V_{CE}=5V$ $R_G=10K\Omega$ $f=10Hz-10kHz$
					3		2	dB	$-I_C=250\mu A$ $-V_{CE}=5V$ $R_G=1K\Omega$ $f=1kHz$